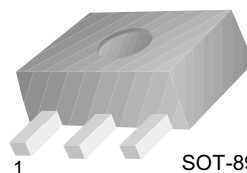


KSD1621

KSD1621

High Current Driver Applications

- Low Collector-Emitter Saturation Voltage
- Large Current Capacity and Wide SOA
- Fast Switching Speed
- Complement to KSB1121



1. Base 2. Collector 3. Emitter

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{CBO}	Collector-Base Voltage	30	V
V_{CEO}	Collector-Emitter Voltage	25	V
V_{EBO}	Emitter-Base Voltage	6	V
I_C	Collector Current	2	A
P_C	Collector Dissipation	500	mW
P_C^*		1.3	W
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature	-55 ~ 150	$^\circ\text{C}$

* Mounted on Ceramic Board (250mm \times 0.8mm)

Electrical Characteristics $T_a=25^\circ\text{C}$ unless otherwise noted

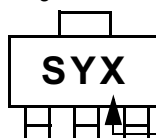
Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
BV_{CBO}	Collector-Base Breakdown Voltage	$I_C=10\mu\text{A}$, $I_E=0$	30			V
BV_{CEO}	Collector-Emitter Breakdown Voltage	$I_C=1\text{mA}$, $I_B=0$	25			V
BV_{EBO}	Emitter-Base Breakdown Voltage	$I_E=10\mu\text{A}$, $I_C=0$	6			V
I_{CBO}	Collector Cut-off Current	$V_{CB}=20\text{V}$, $I_E=0$			100	nA
I_{EBO}	Emitter Cut-off Current	$V_{BE}=4\text{V}$, $I_C=0$			100	nA
h_{FE1} h_{FE2}	DC Current Gain	$V_{CE}=2\text{V}$, $I_C=0.1\text{A}$ $V_{CE}=2\text{V}$, $I_C=1.5\text{A}$	100 65		560	
$V_{CE}(\text{sat})$	Collector-Emitter Saturation Voltage	$I_C=1.5\text{A}$, $I_B=75\text{mA}$		0.18	0.4	V
$V_{BE}(\text{sat})$	Base-Emitter Saturation Voltage	$I_C=1.5\text{A}$, $I_B=75\text{mA}$		0.85	1.2	V
f_T	Current Gain Bandwidth product	$V_{CE}=10\text{V}$, $I_C=50\text{mA}$		150		MHz
C_{ob}	Output Capacitance	$V_{CB}=10\text{V}$, $I_E=0$, $f=1\text{MHz}$		19		pF
t_{ON}	* Turn On Time	$V_{CC}=12\text{V}$, $V_{BE}=5\text{V}$ $I_{B1}=-I_{B2}=25\text{mA}$ $I_C=0.5\text{A}$, $R_L=25\Omega$		60		ns
t_{STG}	* Storage Time			500		ns
t_F	* Fall Time			25		ns

* Pulse Width=20 μs , Duty Cycle \leq 1%

h_{FE} Classification

Classification	R	S	T	U
h_{FE}	100 ~ 200	140 ~ 280	200 ~ 400	280 ~ 560

Marking



h_{FE} grade

Typical Characteristics

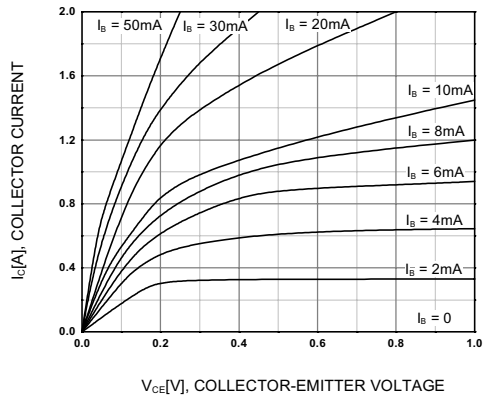


Figure 1. Static Characteristic

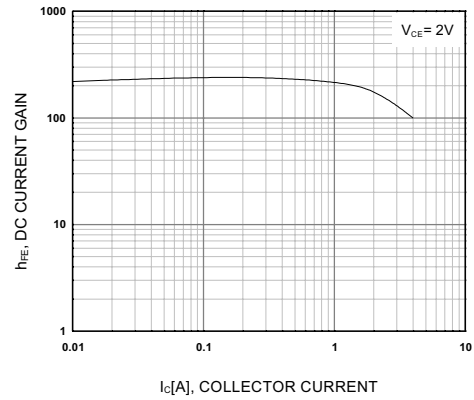


Figure 2. DC current Gain

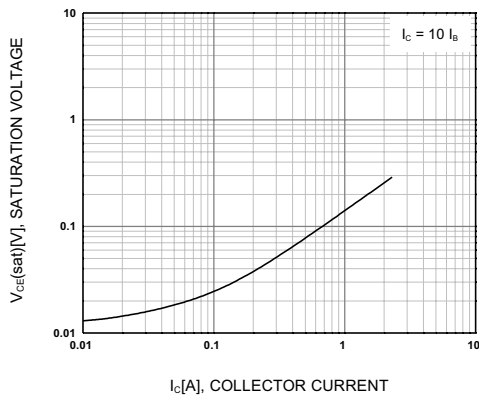


Figure 3. Collector-Emitter Saturation Voltage

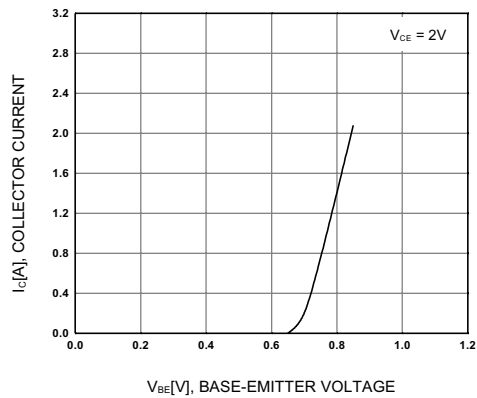


Figure 4. Base-Emitter On Voltage

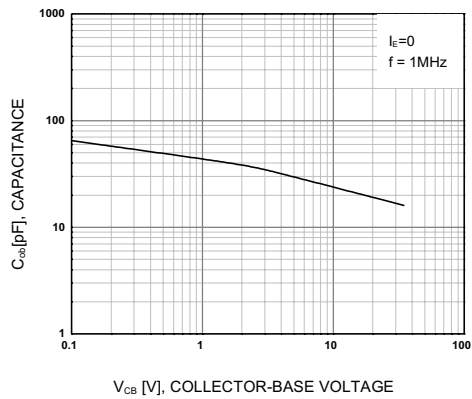


Figure 5. Collector Output Capacitance

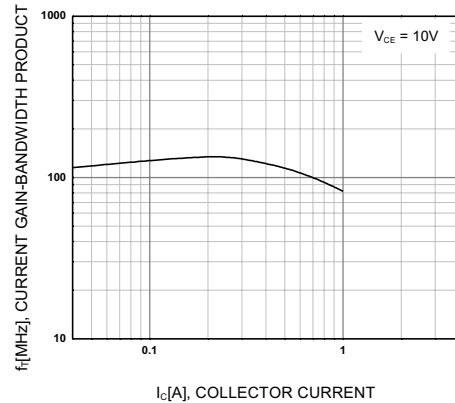


Figure 6. Current Gain Bandwidth Product

Typical Characteristics (Continued)

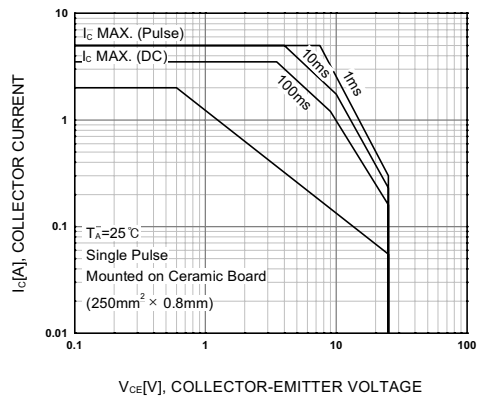


Figure 7. Safe Operating Area

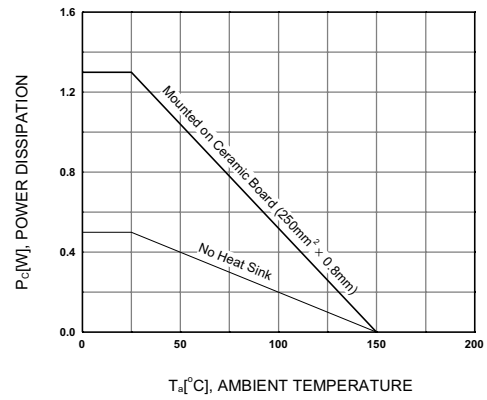
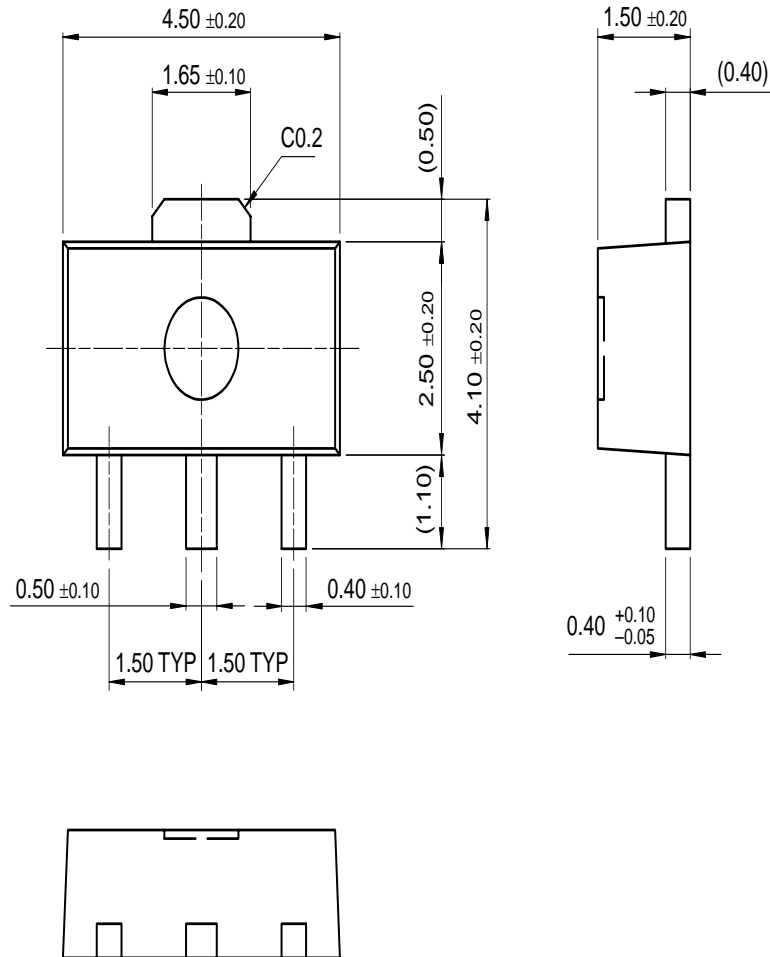


Figure 8. Power Derating

Package Dimensions

SOT-89



Dimensions in Millimeters

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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